Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
BRS	L1	720	LDMOS$2 or LD-MOS$2 or (LD adj MOS$3) or LDMOSFET$1 or LD-MOSFET$1 or (LD adj MOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:33			0
BRS	L2	51	lateral$4 adj diffus$5 adj metal adj oxide adj semiconduct$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:33			0
BRS	L3	60	lateral$4 adj diffus$5 adj (MOS$3 or MOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:34			0
BRS	L4	479	LDDMOS$2 or LDD-MOS$2 or (LDD adj MOS$3) or LDDMOSFET$1 or LDD-MOSFET$1 or (LDD adj MOSFET$1).	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:37			0
BRS	L5	74	(lateral$4 adj double adj diffus$5 adj metal adj oxide adj semiconduct$4) or (lateral$4 adj double-diffus$5 adj metal adj oxide adj semiconduct$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:38			0
BRS	L6	0	lateral$4 adj diffus$5 adj double adj metal adj oxide adj semiconduct$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:39			0
BRS	L7	178	lateral$4 adj double adj diffus$5 adj (MOS$3 or MOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB				0

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
8	BRS	L8	0	lateral$4 adj diffus$5 adj double adj (MOS$3 or MOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:39			0
9	BRS	L9	249	lateral$4 near7 (metal adj oxide adj semiconduct$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:40			0
10	BRS	L10	2322	lateral$4 near7 (MOS or MOSFET$1 or NMOS or NMOSFET$1 or PMOS or PMOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 13:12			0
11	BRS	L11	10	LDPMOS$2 or LD-PMOS$2 or (LD adj PMOS$3) or LDPMOSFET$1 or LD-PMOSFET$1 or (LD adj PMOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:42			0
12	BRS	L12	5	LDNMOS$2 or LD-NMOS$2 or (LD adj NMOS$3) or LDNMOSFET$1 or LD-NMOSFET$1 or (LD adj NMOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:43			0
13	BRS	L13	18145	LDD$1 or "LDD" or ((light$3 adj dop$3) adj (source$1 or drain$1)) or (lightly-doped adj (source$1 or drain$1)) or ((shallow or extension$1) near4 (source$1 or drain$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:45			0

Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
14 BRS	L14	152308	(gate$1 or electrode$1) and source$1 and drain$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:46			0
15 BRS	L15	140917	(field adj (oxide$1 or isolat$5)) or LOCOS$2 or trench$2 or STI$1 or (shallow adj trench$2 adj isolat$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:47			0
16 BRS	L16	3315	1 or 2 or 3 or 4 or 5 or 6 or 7 or 8 or 9 or 10 or 11 or 12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 13:14			0
17 BRS	L17	533	16 and 13 and 14 and 15	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:50			0
18 BRS	L18	73	(1 or 2 or 3) and 13 and 15	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 11:51			0
19 BRS	L19	455	lateral$4 near7 (DMOS or DMOSFET$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 13:13			0
20 BRS	L20	3486	1 or 2 or 3 or 4 or 5 or 6 or 7 or 8 or 9 or 10 or 11 or 12 or 19	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 13:14			0

Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Error errors
21 BRS	L21	547	20 and 13 and 14 and 15	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 13:16			0
22 IS&R	L22	387	("438/286").CCLS.	USPAT; US-PGPUB	2002/03/14 16:16			0
23 BRS	L23	40	21 and 22	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/03/14 16:17			0
24 IS&R	L24	1	("6255154").PN.	USPAT; US-PGPUB	2002/03/14 18:21			0
25 BRS	L25	0	6255154.URPN.	USPAT; US-PGPUB	2002/03/14 18:20			0
26 IS&R	L26	9	(("5382536") or ("5517046") or ("5541435") or ("5578514") or ("5844272") or ("5854566") or ("5869371") or ("6033948") or ("6051482")).PN.	USPAT; US-PGPUB	2002/03/14 18:23			0
27 IS&R	L27	1	("5541123").PN.	USPAT; US-PGPUB	2002/03/14 19:11			0